## NSN 5962-01-337-0171

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range: -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius Features Provided: Burn in and electrostatic sensitive and programmed Inclosure Material: Ceramic Inclosure Configuration: Dual-in-line Output Logic Form: Complementary-metal oxide-semiconductor logic Input Circuit Pattern: 17 input
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Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Memory Device Type:
Rom
Terminal Type And Quantity:
28 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0